

## Advanced European Infrastructures for Detectors at Accelerators

# WP7 - 2<sup>nd</sup> Annual Meeting Introdution

Anna Macchiolo, Iván Vila 4/4/2017

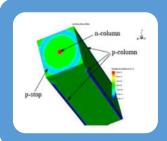




- Review of Milestones & deliverables.
- Common sensor production at CNM and FBK.
- Goals for the meeting.



#### Overview: Tasks



#### **Device Simulation**

- Layout optimization.
- Radiation damage modeling
- Optimization signal multiplication structures.



#### Sensor manufacturing

- Development & improvement of manufacturing processes for planar, 3D and LGAD devices.
- MPWR for thinned 3D and slim/active edge planar.















#### Detector performance assessment

- Hybrid thin planar & 3D pixels for HL-LHC environment.
- Very small size and thin pixel sensors for CLIC.
- Low Gain Avalanche Detectors for timing and tracking









#### Deliverables

#### **Deliverables**

Del. no.	Deliverable name	WP no.	Planned delivery date	Actual delivery date	Status	Comments
D7.1	Simulation of 3D pixel sensor cells	7	M18	04/11/2016	Achieved	Report
D7.2	Simulation active edge sensors	7	M18	04/11/2016	Achieved	Report
D7.3	LGAD simulation	7	M18	04/11/2016	Achieved	Report
D7.4	TCAD model radiation damage	7	M46			
D7.5	Wafer Layout MPW run	7	M30			
D7.6	Initial pixel characterisation	7	M24		•	
D7.7	Final pixel characterisation	7	M46			
D7.8	LGAD characterisation	7	M46			

### Milestones

#### Milestones

Mil. no.	Milestone name	WP no.	Planned delivery date	Actual delivery date	Status	Comments
MS29	Validation and release of TCAD simulation	7	M16	02/09/2016	Achieved	Report
MS49	Workshop on 3D-planar	7	M24			
MS50	LGAD thickness technological choice	7	M24			
MS51	LGAD Workshop on the characterisation results of the available LGAD sensors	7	M24			
MS81	Test beam campaign for 3D and planar sensors	7	M36			
MS87	MPW runs completion	7	M42			
MS98	Validation radiation damage model with data comparison	7	M46			



### **Publications**

<b>CERN Document Server</b>			
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(main) ; TIFPA-INFN, Trento) ; Boscardin TIFPA-INFN, Trento)	n, Maurizio (Fond. Bruno Kessler, Tre	ento ; TIFPA-INFN, Trento) ; R	INFN, Trento); Dalla Betta, Gian-Franco (U. Trento (main); TIFPA-INFN, Trento); Mendicino, Roberto (U. Trento; Ronchin, Sabina (Fond. Bruno Kessler, Trento; TIFPA-INFN, Trento); Zorzi, Nicola (Fond. Bruno Kessler, Trento; Indidates for the innermost tracking layers of the forthcoming experiment upgrades at the Phase 2 High-
Luminosity LHC (HL-LHC). To this purpo	ose, extreme radiation hardness up	to the expected maximum flo	fluence of 2e16 neq.cm-2 must come along with several technological improvements in a new generation of 3D um), narrower columnar electrodes (~5 um diameter) with reduced inter-electrode spacing (~30 um), and very
slim edges (~100 um). []			
arXiv:1612.00638 2017 - 8 p Publisi In : 18th International Workshop on Ra	, , ,	•	nn (01022
Detailed record - Similar records	diation imaging Detectors, Darcetor	ia, 5pain, 65 67 fat 2010, p	pp.co1022
			or high energy physics applications / Carulla, M. (IMB-CNM (CSIC)) ; Fernández-García, M. ;IFCA (CSIC-UC) ;
Fernández-Martínez, P.; IMB-CNM (CSIC	.); Flores, D.; IMB-CNM (CSIC); Gor	zález, J. (IFCA (CSIC-UC)); Hi	Hidalgo, S. (IMB-CNM (CSIC)) ; Jaramillo, R. (IFCA(CSIC-UC)) ; Merlos, A. (IMB-CNM (CSIC-UC)) ; Palomo, F.R.



## Common sensor productions

At least three common productions foreseen in WP7, one for each technology

- Processing of MPWR for 3D and planar pixel sensors on thinned substrates, compatible with the RD53 chip
- Common submission of LGAD sensors
  - Prototyping of LGAD sensors on thin substrates.

Deliverable	Responsible Group	Month due	
D7.5 Wafer Layout MPW	CSIC	M30 (OCT 2017)	
Milestone	Responsible Group	Month due	
MS87 MPW runs completion	CSIC	M42 (OCT 2018)	

**3D** production at FBK about to start.

**Active edge** production at FBK second half 2017, trench technology to be defined with test wafers or test batches beforehand

**3D** production at CNM already started..

**LGAD** production at CNM to be decided during this meeting.



### Goals of this meeting

- Converge on the technology and the devices to be included in the LGAD Common Run
- Continue the discussion on the active planar common Run, not to be closed today.
- Define the devices and groups to participate on the coming WP7 Test beam at SPS (baseline to continue the activities of the last year test-beam)

### Agenda

	Introduction	Anna Macchiolo et al.
	Salle des séminaires- 1222-RC-08, LPNHE	14:30 - 14:40
	Discussion on common LGAD production	Nicolo Cartiglia
	Salle des séminaires- 1222-RC-08, LPNHE	14:40 - 15:00
15:00	3D pixel sensors in Trento: update on activities and plans	Gian Franco Dalla Betta et al. 🥝
	Salle des séminaires- 1222-RC-08, LPNHE	15:00 - 15:20
	Development of a radiation model for TCAD simulations	Ariahha Morozzi
	Salle des séminaires- 1222-RC-08, LPNHE	15:20 - 15:40
	Update on small-pitch active-edge planar sensor studies for the CLIC vertex detector	Dominik Dannheim
	Salle des séminaires- 1222-RC-08, LPNHE	15:40 - 16:00
16:00	Update on activites in Manchester	Cinzia Da Via
	Salle des séminaires- 1222-RC-08, LPNHE	16:00 - 16:20
	Coffee break	
	Amphi Charpak	16:20 - 16:30
	Update on activities at MPP	Ahha Macchiolo
	Salle des séminaires- 1222-RC-08, LPNHE	16:30 - 16:50
	3D and Planar Pixel Sensors Results and Plans in Florence	Marco Meschihi
17:00	Salle des séminaires- 1222-RC-08, LPNHE	16:50 - 17:10
	Status of Lgad technology for timing applications	Giulio Pellegrihi
	Salle des séminaires- 1222-RC-08, LPNHE	17:10 - 17:30
	Update on activities at Santander	Ivan Vila Alvarez
	Salle des séminaires- 1222-RC-08, LPNHE	17:30 - 17:50
	Common discussion on WP7 planar active edge production	Maurizio Boscardin 🥝

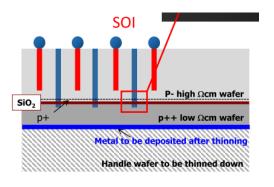


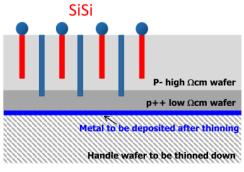
### **THANK YOU!**

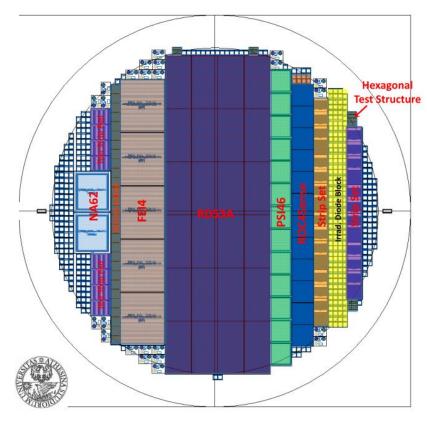


## 3D Common production @ FBK

- Single-sided process
- "Thin" active layer (130 μm): SiSi or SOI
- Ohmic columns depth > active layer
- Junction columns depth < active layer</li>
- Column diameter ~ 5 um
- Holes partially filled with poly
- Very slim edge (100 μm)









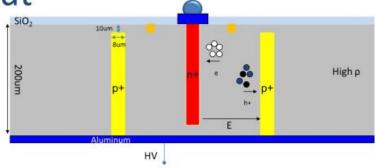
## 3D Common Production @ CNM

• Ready to start this week.

Run XXXX: mask layout

Mask: CNM840

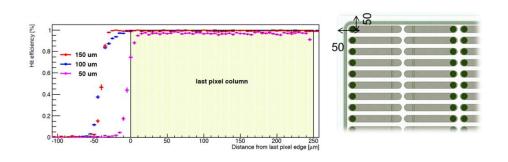


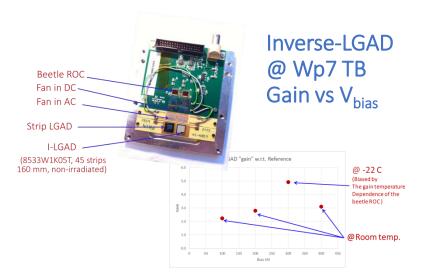


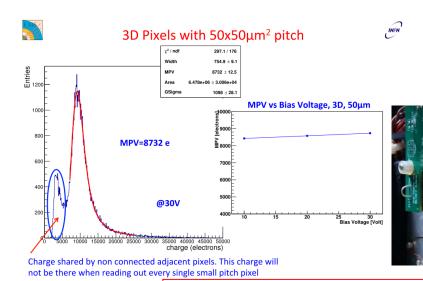
- 9 RD53 50x50um<sup>2</sup> (1-x)
- 9 RD53 25x100um<sup>2</sup> 2E (2-x)
- 2 RD53 25x100um<sup>2</sup> 1E (3-x)
- 9 Diodes 50x50um<sup>2</sup> (5-x)
- 16 Diodes (small) 50x50um<sup>2</sup> (6-x)
- 6 Diodes 25x50um (7-x)
- 6 Diodes 25x100um<sup>2</sup> (8-x)
- 4 MOS (9-x)



### Results Snapshot





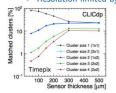


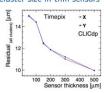
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Micron/2A assenticity

| 100 | Timepix3 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 | 100 |

- ► Test beam studies on sensor assemblies with different thickness (Micron, Advacam) using Timepix(3) readout ASICs, 55 µm pitch
- ► Thinnest assembly: 100 μm sensor on 100 μm Timepix ASIC
- ► Study performance of thin planar sensors
  - High detection efficiency even for 50 µm thin sensor under normal operating conditions
  - ► Resolution limited by cluster size in thin sensors





December 2016 Test Beam Setup at Fermilab



## Progress report: 2016 TB @ SPS

- First WP7 Test Beam @ CERN-SPS from July 27<sup>th</sup> through August 3 + one additional week parasitically with Atlas ITK
- The use of the ATLAS tracker/vertex test beam infrastructure (motor stages, cooling box, etc) was capital (and support from A. Macchiolo team support)
- Telescope: ACONITE (AIDA telescope)
- Devices:
  - 50x50 mm<sup>2</sup> 3D pixel strips: non-irradiated (CNM)
  - 25x100 mm<sup>2</sup> 3D pixel strips: non-irradiated (CNM)
  - 25x100 mm<sup>2</sup> 3D pixel strips: 7x10<sup>15</sup> n<sub>eq</sub>/cm<sup>2</sup> protons (CNM)
  - I-LGAD (p-in-p strip LGADs) (CNM)
  - Thinned planar pixel detectors (50um, 100um & 150um) slim/active edges from Advacam (FE-I4 footprint), fresh and irradiated (10<sup>15</sup> n<sub>eq</sub> cm<sup>-2</sup>)
  - THIN n-in-p pixel sensors 130μm and 100μm active thickness (PSI46dig footprint), fresh and proton irradiated (8.3E15 p/cm2)





